

# Toh-Ming Lu

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/8904826/publications.pdf>

Version: 2024-02-01

71  
papers

2,239  
citations

236612  
25  
h-index

223531  
46  
g-index

72  
all docs

72  
docs citations

72  
times ranked

4360  
citing authors

#	ARTICLE	IF	CITATIONS
1	Aging of Transition Metal Dichalcogenide Monolayers. <i>ACS Nano</i> , 2016, 10, 2628-2635.	7.3	359
2	Transitionâ€Metal Substitution Doping in Synthetic Atomically Thin Semiconductors. <i>Advanced Materials</i> , 2016, 28, 9735-9743.	11.1	208
3	Photon Transport in One-Dimensional Incommensurately Epitaxial CsPbX <sub>3</sub> Arrays. <i>Nano Letters</i> , 2016, 16, 7974-7981.	4.5	124
4	A chiral switchable photovoltaic ferroelectric 1D perovskite. <i>Science Advances</i> , 2020, 6, eaay4213.	4.7	119
5	Î²-phase tungsten nanorod formation by oblique-angle sputter deposition. <i>Applied Physics Letters</i> , 2003, 83, 3096-3098.	1.5	116
6	Carrier lifetime enhancement in halide perovskite via remote epitaxy. <i>Nature Communications</i> , 2019, 10, 4145.	5.8	93
7	Low temperature melting of copper nanorod arrays. <i>Journal of Applied Physics</i> , 2006, 99, 064304.	1.1	81
8	Stress reduction in tungsten films using nanostructured compliant layers. <i>Journal of Applied Physics</i> , 2004, 96, 5740-5746.	1.1	63
9	Enhanced step coverage by oblique angle physical vapor deposition. <i>Journal of Applied Physics</i> , 2005, 97, 124504.	1.1	57
10	Traditional Semiconductors in the Two-Dimensional Limit. <i>Physical Review Letters</i> , 2018, 120, 086101.	2.9	52
11	An Environmentally Stable and Leadâ€Free Chalcogenide Perovskite. <i>Advanced Functional Materials</i> , 2020, 30, 2001387.	7.8	52
12	A Method Toward Fabricating Semiconducting 3R-NbS <sub>2</sub> Ultrathin Films. <i>Journal of Physical Chemistry C</i> , 2015, 119, 19763-19771.	1.5	50
13	Utilizing van der Waals Slippery Interfaces to Enhance the Electrochemical Stability of Silicon Film Anodes in Lithium-Ion Batteries. <i>ACS Applied Materials &amp; Interfaces</i> , 2018, 10, 13442-13451.	4.0	48
14	High-Crystallinity Epitaxial Sb <sub>2</sub> Se <sub>3</sub> Thin Films on Mica for Flexible Near-Infrared Photodetectors. <i>ACS Applied Materials &amp; Interfaces</i> , 2020, 12, 35222-35231.	4.0	47
15	Stress reduction in sputter deposited films using nanostructured compliant layers by high working-gas pressures. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2005, 23, 986-990.	0.9	43
16	Water electrolysis activated by Ru nanorod array electrodes. <i>Applied Physics Letters</i> , 2006, 88, 263106.	1.5	42
17	A two-step dry process for Cs <sub>2</sub> SnI <sub>6</sub> perovskite thin film. <i>Materials Research Letters</i> , 2017, 5, 540-546.	4.1	40
18	van der Waals Epitaxy of Antimony Islands, Sheets, and Thin Films on Single-Crystalline Graphene. <i>ACS Nano</i> , 2018, 12, 6100-6108.	7.3	38

#	ARTICLE	IF	CITATIONS
19	Theoretical and Experimental Insight into the Mechanism for Spontaneous Vertical Growth of ReS <sub>2</sub> Nanosheets. <i>Advanced Functional Materials</i> , 2018, 28, 1801286.	7.8	35
20	Room-temperature electrically switchable spin-valley coupling in a van der Waals ferroelectric halide perovskite with persistent spin helix. <i>Nature Photonics</i> , 2022, 16, 529-537.	15.6	35
21	A Reconfigurable Remotely Epitaxial VO <sub>2</sub> Electrical Heterostructure. <i>Nano Letters</i> , 2020, 20, 33-42.	4.5	33
22	Evidence of enhanced electron-phonon coupling in ultrathin epitaxial copper films. <i>Applied Physics Letters</i> , 2013, 103, .	1.5	31
23	Van Der Waals Hybrid Perovskite of High Optical Quality by Chemical Vapor Deposition. <i>Advanced Optical Materials</i> , 2017, 5, 1700373.	3.6	27
24	Revealing the Crystalline Integrity of Wafer-Scale Graphene on SiO <sub>2</sub> /Si: An Azimuthal RHEED Approach. <i>ACS Applied Materials &amp; Interfaces</i> , 2017, 9, 23081-23091.	4.0	27
25	Monolayer MoS <sub>2</sub> on sapphire: an azimuthal reflection high-energy electron diffraction perspective. <i>2D Materials</i> , 2021, 8, 025003.	2.0	26
26	CdTe/ZnTe/GaAs Heterostructures for Single-Crystal CdTe Solar Cells. <i>Journal of Electronic Materials</i> , 2014, 43, 2895-2900.	1.0	25
27	van der Waals epitaxy of CdS thin films on single-crystalline graphene. <i>Applied Physics Letters</i> , 2017, 110, .	1.5	24
28	Epitaxial CdTe Thin Films on Mica by Vapor Transport Deposition for Flexible Solar Cells. <i>ACS Applied Energy Materials</i> , 2020, 3, 4589-4599.	2.5	24
29	Tera Tool [terahertz time-domain spectroscopy]. <i>IEEE Circuits and Devices: the Magazine of Electronic and Photonic Systems</i> , 2002, 18, 23-28.	0.8	22
30	Unique structure/properties of chemical vapor deposited poly(ethylene). <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2002, 20, 1445-1449.	0.9	20
31	Kinetics of Ta ions penetration into porous low-k dielectrics under bias-temperature stress. <i>Applied Physics Letters</i> , 2010, 96, 222901.	1.5	20
32	Dielectric constant measurement of thin films using goniometric terahertz time-domain spectroscopy. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2001, 7, 624-629.	1.9	18
33	A review on low dimensional metal halides: Vapor phase epitaxy and physical properties. <i>Journal of Materials Research</i> , 2017, 32, 3992-4024.	1.2	18
34	Effects of three-dimensional Ehrlich-Schwoebel barrier on texture selection during Cu nanorod growth. <i>Applied Physics Letters</i> , 2007, 91, 121914.	1.5	16
35	Large Metallic Vanadium Disulfide Ultrathin Flakes for Spintronic Circuits and Quantum Computing Devices. <i>ACS Applied Nano Materials</i> , 2019, 2, 3684-3694.	2.4	14
36	Single-Crystal CdTe Homojunction Structures for Solar Cell Applications. <i>Journal of Electronic Materials</i> , 2015, 44, 3118-3123.	1.0	12

#	ARTICLE	IF	CITATIONS
37	Metalorganic vapor phase epitaxy of large size CdTe grains on mica through chemical and van der Waals interactions. <i>Physical Review Materials</i> , 2018, 2, .	0.9	12
38	van der Waals epitaxial ZnTe thin film on single-crystalline graphene. <i>Journal of Applied Physics</i> , 2018, 123, .	1.1	11
39	Nonlinear Electron-Lattice Interactions in a Wurtzite Semiconductor Enabled via Strongly Correlated Oxide. <i>Advanced Materials</i> , 2016, 28, 8975-8982.	11.1	10
40	Enhanced photoemission from nanostructured surface topologies. <i>Applied Physics Letters</i> , 2006, 89, 193116.	1.5	9
41	Quasi van der Waals epitaxy of copper thin film on single-crystal graphene monolayer buffer. <i>Journal Physics D: Applied Physics</i> , 2018, 51, 095301.	1.3	9
42	Anisotropic band structure of TiS3 nanoribbon revealed by polarized photocurrent spectroscopy. <i>Applied Physics Letters</i> , 2020, 117, .	1.5	8
43	Tuning phase transition kinetics via van der Waals epitaxy of single crystalline VO2 on hexagonal-BN. <i>Journal of Crystal Growth</i> , 2020, 543, 125699.	0.7	8
44	Introduction of molecular scale porosity into semicrystalline polymer thin films using supercritical carbon dioxide. <i>Applied Physics Letters</i> , 2009, 94, 121908.	1.5	7
45	Vertically aligned biaxially textured molybdenum thin films. <i>Journal of Applied Physics</i> , 2011, 110, .	1.1	7
46	Surface area and porosity in obliquely grown photocatalytic titanium dioxide for air purification. <i>Journal of Applied Physics</i> , 2014, 115, .	1.1	7
47	Modular Approach for Metal-Semiconductor Heterostructures with Very Large Interface Lattice Misfit: A First-Principles Perspective. <i>Crystal Growth and Design</i> , 2016, 16, 2328-2334.	1.4	7
48	Decoupling interface effect on the phase stability of CdS thin films by van der Waals heteroepitaxy. <i>Applied Physics Letters</i> , 2017, 110, 041602.	1.5	7
49	Probing the interface strain in a 3D-2D van der Waals heterostructure. <i>Applied Physics Letters</i> , 2017, 111, .	1.5	7
50	Single-Crystal Graphene-Directed van der Waals Epitaxial Resistive Switching. <i>ACS Applied Materials &amp; Interfaces</i> , 2018, 10, 6730-6736.	4.0	7
51	Coherent Phonon Transport Measurement and Controlled Acoustic Excitations Using Tunable Acoustic Phonon Source in GHz-sub THz Range with Variable Bandwidth. <i>Scientific Reports</i> , 2018, 8, 7054.	1.6	7
52	Large scale epitaxial graphite grown on twin free nickel(111)/spinel substrate. <i>CrystEngComm</i> , 2020, 22, 119-129.	1.3	7
53	Residual Stress Reduction in Sputter Deposited Thin Films by Density Modulation. <i>Materials Research Society Symposia Proceedings</i> , 2009, 1224, 1.	0.1	6
54	Growth of CdTe Films on Amorphous Substrates Using CaF2 Nanorods as a Buffer Layer. <i>Journal of Electronic Materials</i> , 2009, 38, 1600-1604.	1.0	6

#	ARTICLE	IF	CITATIONS
55	Orientation-Controlled Large-Area Epitaxial PbI <sub>2</sub> Thin Films with Tunable Optical Properties. ACS Applied Materials & Interfaces, 2021, 13, 32450-32460.	4.0	6
56	Domain boundaries in incommensurate epitaxial layers on weakly interacting substrates. Journal of Applied Physics, 2021, 130, 065301.	1.1	5
57	Coherent acoustic vibrations in silicon submicron spiral arrays. Journal of Applied Physics, 2009, 106, 033517.	1.1	4
58	Unit-Cell-Thick Oxide Synthesis by Film-Based Scavenging. Journal of Physical Chemistry C, 2020, 124, 8394-8400.	1.5	4
59	Enhanced van der Waals epitaxy via electron transfer enabled interfacial dative bond formation. Physical Review Materials, 2017, 1, .	0.9	4
60	Growth front smoothing effects in extremely high pressure vapor deposition. Scientific Reports, 2020, 10, 12355.	1.6	2
61	Reflection High-energy Electron Diffraction Study of Nanostructures: From Diffraction Patterns to Surface Pole Figure. Materials Research Society Symposia Proceedings, 2009, 1184, 62.	0.1	1
62	Method to Determine the Root Cause of Low- $\kappa$ SiCOH Dielectric Failure Distributions. IEEE Electron Device Letters, 2017, 38, 119-122.	2.2	1
63	The Development of the Charge Transport Model To Predict Dielectric Failure. , 2018, , .		1
64	Contact potential induced carrier localization in nanometer-thin Cu/Ru, Cu/Co, and Cu/Mo superlattices. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2020, 38, .	0.9	1
65	Heteroepitaxy of High-Mobility Germanium on Sapphire (0001) with Magnetron Sputtering. ACS Applied Electronic Materials, 2020, 2, 1635-1644.	2.0	1
66	Dielectric, Conducting, and Photonic Polymers for Devices in Multichip Packaging. Materials Research Society Symposia Proceedings, 1989, 154, 387.	0.1	0
67	Measurement of the dielectric constant of thin films using goniometric time-domain spectroscopy. AIP Conference Proceedings, 2001, , .	0.3	0
68	Fabrication and Imaging of Protein Crossover Structures. Materials Research Society Symposia Proceedings, 2002, 735, 361.	0.1	0
69	Lithography for sub>30 nm design rules: materials challenges. , 0, , .		0
70	Novel Ultrathin Mg Nanoblades for Hydrogen Storage. Materials Research Society Symposia Proceedings, 2009, 1216, 1.	0.1	0
71	RHEED Pole Figure Measurements of Biaxial Thin Film Growth Front Evolution. Materials Research Society Symposia Proceedings, 2011, 1308, 40201.	0.1	0